S9-X36HXX-X Series CMOS VCXO

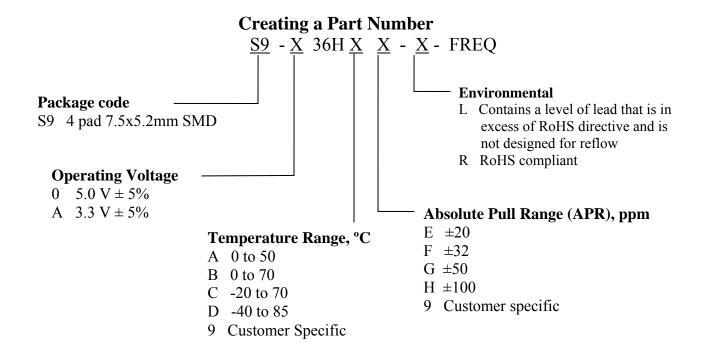
Rev. G

Description

The S9-X36HXX Series of voltage controlled crystal oscillators (VCXO) provides low phase noise CMOS output. The device packaged in a miniature, low profile, leadless FR-4 based package with gold plated pads, which enhances compatibility with PCB material.

Applications and Features

- Low Phase Noise
- Wimax, Fiber Channel; 10 GbE; Infiniband; Network Processors; SOHO Routing
- High Reliability NEL HALT/HASS qualified for crystal oscillator start-up conditions
- Low cost
- COTS/Dual use

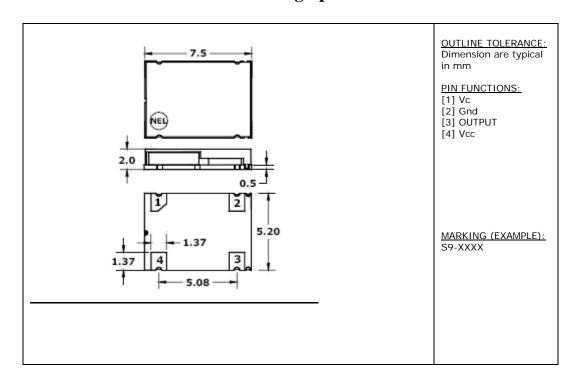




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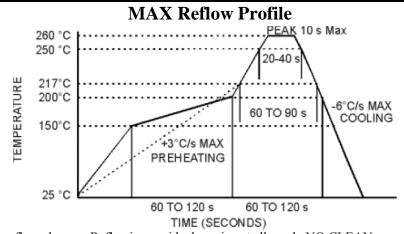
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Rev. G Drawing Specification



Environmental and Mechanical Characteristics

Operating temp.	see part # table			
Range				
Mechanical Shock	Per MIL-STD-202, Method 213, Cond. A			
Thermal Shock	Per MIL-STD-883, Method 1011, Cond. A			
Vibration	Per MIL-STD-883, Method 2007, Cond. A			
Hermetic Seal	Leak rate less than 1x10 ⁻⁸ atm.cc/s of helium, crystal only.			
Soldering conditions	See MAX reflow profile below; The device may be reflowed once. Reflowing upside down is not			
	allowed. NO CLEAN assembly is recommended.			



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Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Operating Temperature Range	То	-40 to +85	°C
Storage Temperature Range	Tst	-50 to +90	°C
Supply Voltage	Vcc	-0.5 to 5.5	V
Control Voltage	Vc	-0.5 to 5.5	

Electrical Parameters (2)

Parameter		Symb	b Conditions, Note		MIN	TYP	MAX	Unit
Nominal Frequency		Fo			1		220	MHz
Supply Voltage		Vcc	Code 0 Code A		4.75 3.135	5.0 3.3	5.25 3.465	V
Supply cur	rent	Icc	@155 MHz, 3.3V		3.133	40	60	mA
Output Logic Type						CMOS		
Load						15 pF/10 KOhm		Ohm
Output Levels		Voh Vol	overall		0.9Vcc	TC/IIII	0.1 Vcc	V
Duty Cycle (Symmetry)		7 01	At 50% Vcc		45/55	50/50	55/45	%
Rise/Fall Time		Tr/Tf	0.2Vcc to 0.8 Vcc; F< 70 MHz 70 MHz <f< 125="" mhz<br="">125MHz<f<220 mhz<="" td=""><td></td><td>3 2 1.5</td><td>5 3 2.5</td><td>ns</td></f<220></f<>			3 2 1.5	5 3 2.5	ns
Jitter	Integrated	J	Integrated from Phase Noise, 12 KHz to 20 MHz, RMS			0.1	0.2	ps
			100Hz to 80H				1.0	ps
			50 KHz to 80 MHz			0.3		ps
	Wavecrest characterized		Random period,			2.5		ps
			Accumul., pk-to-pk			17		ps
			Determin.	F>52 MHz		6		ps
Sub-harmonics			F > 52 MHz			-50	-42	dBc
Phase Noise (1)		£(Δf)	155.52 MHz,	@ 10 Hz @100 Hz @1 KHz @10KHz @100KHz @>1MHz		-70 -100 -125 -140 -145 -145		dBc/Hz
Frequency Stability, usually not specified – unless necessary, APR is specified to incorporate stability		ΔF/F	Overall, including temperature, aging 10 years, shock and vibration @Vc=Vcc/2; APR 50 ppm, or less		±20	±30		ppm
Control Voltage Range		Vc			0V		Vcc	V
Setability		Vcs	Vc to set the F at Fo; T, Vcc, load – nominal, as shipped		0.4 Vcc	0.5 Vcc	0.6 Vcc	V
Absolute Pull Range		APR	Over all conditions, see part # creation		20, 32, 50, 100			ppm
Input impedance		Zin	@ Fmod < 100 KHz		50			KOhm
Modulation Bandwidth			At $Vc = Vcc/2$, $-3dB$		20			KHz

Footnote: 1) If phase noise data at a particular frequency is needed, contact factory.

²⁾ All parameters, unless otherwise specified, are at nominal conditions, ie: T=25°C, Nominal Vcc & Nominal Load.



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